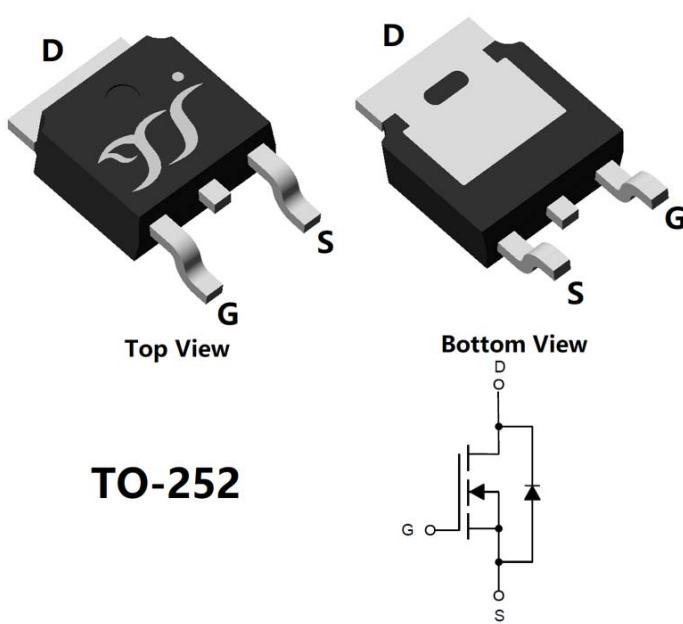


N-Channel Enhancement Mode Field Effect Transistor



Product Summary

- V_{DS} 60V
- I_D 35A
- $R_{DS(ON)}$ (at $V_{GS}=10V$) $<18m\Omega$
- $R_{DS(ON)}$ (at $V_{GS}=4.5V$) $<21m\Omega$
- 100% EAS Tested
- 100% ∇V_{DS} Tested

General Description

- Trench Power LV MOSFET technology
- Excellent package for heat dissipation
- High density cell design for low $R_{DS(ON)}$
- Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free

Applications

- Power switching application
- Uninterruptible power supply
- DC-DC convertor

■ Absolute Maximum Ratings ($T_A=25^\circ C$ unless otherwise noted)

| Parameter | | Symbol | Limit | Unit |
|--|-------------------|----------------|----------|------|
| Drain-source Voltage | | V_{DS} | 60 | V |
| Gate-source Voltage | | V_{GS} | ± 20 | V |
| Drain Current | $T_A=25^\circ C$ | I_D | 5 | A |
| | $T_A=100^\circ C$ | | 3 | |
| | $T_c=25^\circ C$ | | 35 | |
| | $T_c=100^\circ C$ | | 22 | |
| Pulsed Drain Current ^A | | I_{DM} | 100 | A |
| Avalanche energy ^B | | EAS | 68 | mJ |
| Total Power Dissipation ^C | $T_A=25^\circ C$ | P_D | 1.2 | W |
| | $T_A=100^\circ C$ | | 0.5 | |
| | $T_c=25^\circ C$ | | 41 | |
| | $T_c=100^\circ C$ | | 16 | |
| Junction and Storage Temperature Range | | T_J, T_{STG} | -55~+150 | °C |

■ Thermal resistance

| Parameter | | Symbol | Typ | Max | Units |
|---|--------------|-----------------|-----|-----|-------|
| Thermal Resistance Junction-to-Ambient ^D | Steady-State | $R_{\theta JA}$ | 80 | 100 | °C/W |
| Thermal Resistance Junction-to-Case | Steady-State | $R_{\theta JC}$ | 2.4 | 3 | |

■ Ordering Information (Example)

| PREFERRED P/N | PACKING CODE | Marking | MINIMUM PACKAGE(pcs) | INNER BOX QUANTITY(pcs) | OUTER CARTON QUANTITY(pcs) | DELIVERY MODE |
|---------------|--------------|-----------|----------------------|-------------------------|----------------------------|---------------|
| YJD35N06A | F1/F2 | YJD35N06A | 2500 | / | 25000 | 13"Reel |



YJD35N06A

■ Electrical Characteristics (T_J=25°C unless otherwise noted)

| Parameter | Symbol | Conditions | Min | Typ | Max | Units |
|---------------------------------------|---------------------|---|-----|------|------|-------|
| Static Parameter | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} = 0V, I _D =250μA | 60 | - | - | V |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =60V, V _{GS} =0V | - | - | 1 | μA |
| | | V _{DS} =60V, V _{GS} =0V, T _j =150°C | - | - | 100 | |
| Gate-Body Leakage Current | I _{GSS} | V _{GS} = ±20V, V _{DS} =0V | - | - | ±100 | nA |
| Gate Threshold Voltage | V _{GS(th)} | V _{DS} = V _{GS} , I _D =250μA | 1 | 1.5 | 2.5 | V |
| Static Drain-Source On-Resistance | R _{DS(ON)} | V _{GS} =10V, I _D =20A | - | 13.5 | 18 | mΩ |
| | | V _{GS} =4.5V, I _D =15A | - | 15.5 | 21 | |
| Diode Forward Voltage | V _{SD} | I _S =20A, V _{GS} =0V | - | 0.9 | 1.2 | V |
| Gate resistance | R _G | f=1MHz | - | 2 | - | Ω |
| Maximum Body-Diode Continuous Current | I _S | | - | - | 35 | A |
| Dynamic Parameters | | | | | | |
| Input Capacitance | C _{iss} | V _{DS} =30V, V _{GS} =0V, f=1MHz | - | 2000 | - | pF |
| Output Capacitance | C _{oss} | | - | 110 | - | |
| Reverse Transfer Capacitance | C _{rss} | | - | 100 | - | |
| Switching Parameters | | | | | | |
| Total Gate Charge | Q _g | V _{GS} =10V, V _{DS} =30V, I _D =20A | - | 39 | - | nC |
| Gate-Source Charge | Q _{gs} | | - | 5.3 | - | |
| Gate-Drain Charge | Q _{gd} | | - | 9.6 | - | |
| Reverse Recovery Charge | Q _{rr} | I _F =20A, di/dt=350A/us | - | 84 | - | nC |
| Reverse Recovery Time | t _{rr} | | - | 19 | - | ns |
| Turn-on Delay Time | t _{D(on)} | V _{GS} =10V, V _{DD} =30V, I _D =20A R _{GEN} =2.2Ω | - | 7.4 | - | ns |
| Turn-on Rise Time | t _r | | - | 49 | - | |
| Turn-off Delay Time | t _{D(off)} | | - | 27 | - | |
| Turn-off fall Time | t _f | | - | 30 | - | |

- A. Repetitive rating; pulse width limited by max. junction temperature.
- B. T_J=25°C, V_{DD}=55V, V_G=10V, R_G=25Ω, L=0.5mH, IAS=16.5A.
- C. P_d is based on max. junction temperature, using junction-case thermal resistance.
- D. The value of R_{0JA} is measured with the device mounted on 1in2 FR-4 board with 2oz. Copper, in the still air environment with T_A=25°C. The maximum allowed junction temperature of 150°C. The value in any given application depends on the user's specific board design.



YJD35N06A

■Typical Electrical and Thermal Characteristics Diagrams

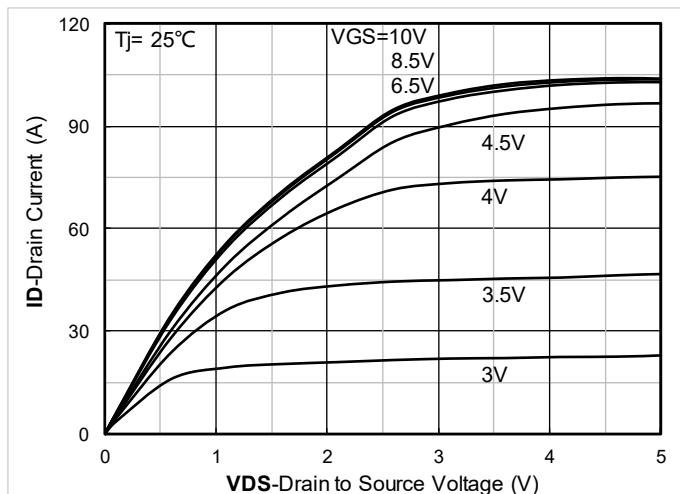


Figure 1. Output Characteristics

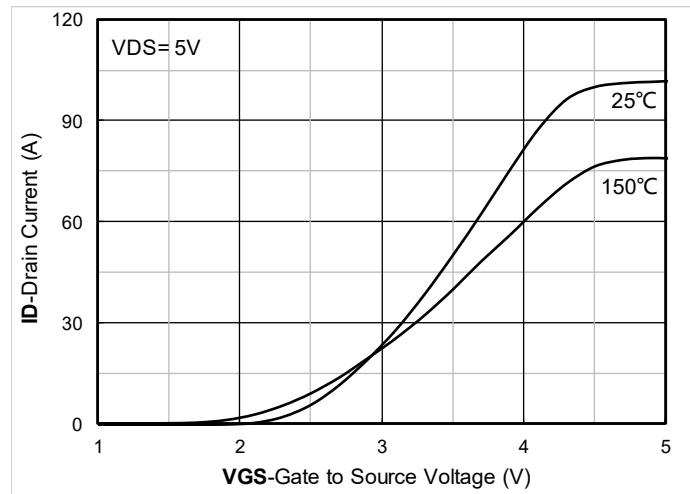


Figure 2. Transfer Characteristics

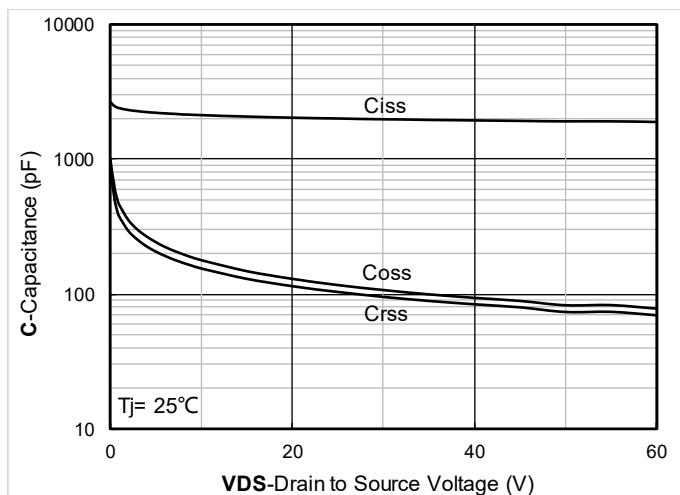


Figure 3. Capacitance Characteristics

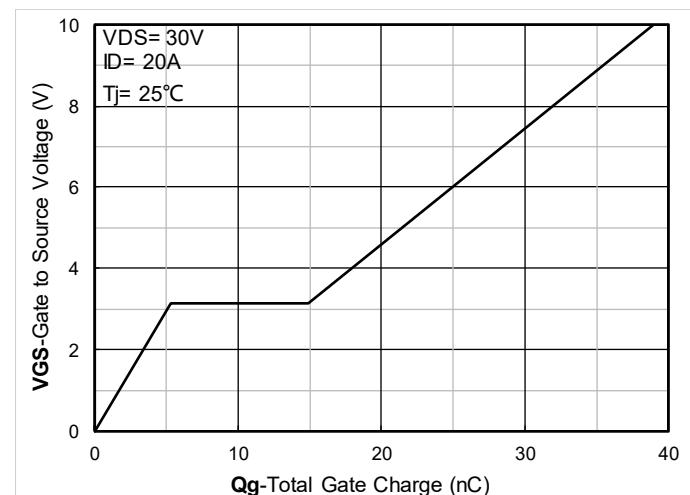


Figure 4. Gate Charge

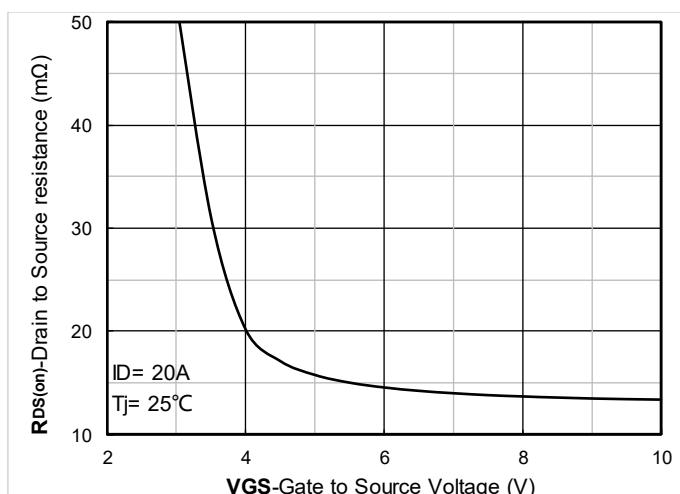


Figure 5. On-Resistance vs Gate to Source Voltage

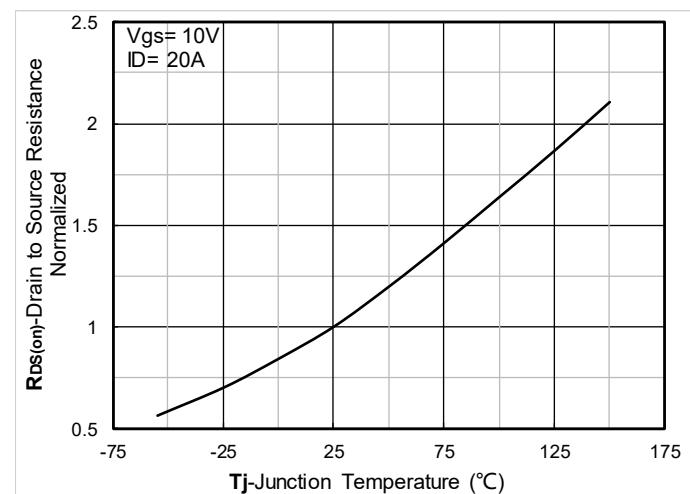


Figure 6. Normalized On-Resistance



YJD35N06A

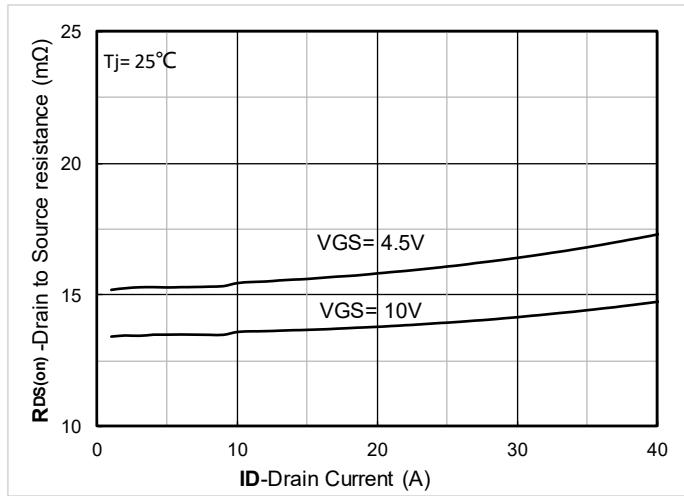


Figure 7. $R_{DS(on)}$ VS Drain Current

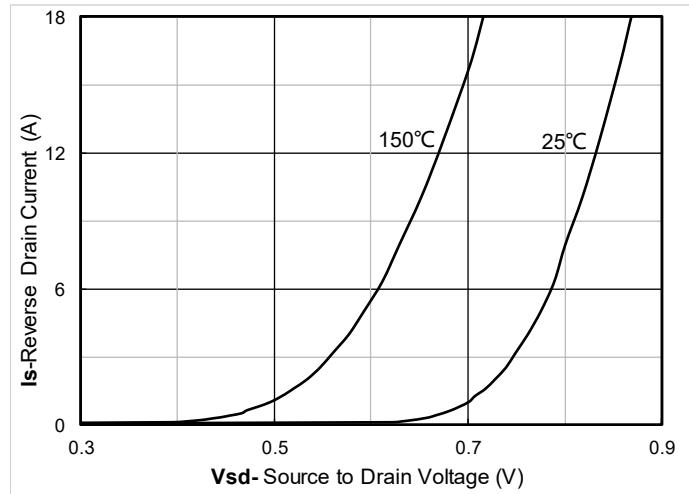


Figure 8. Forward characteristics of reverse diode

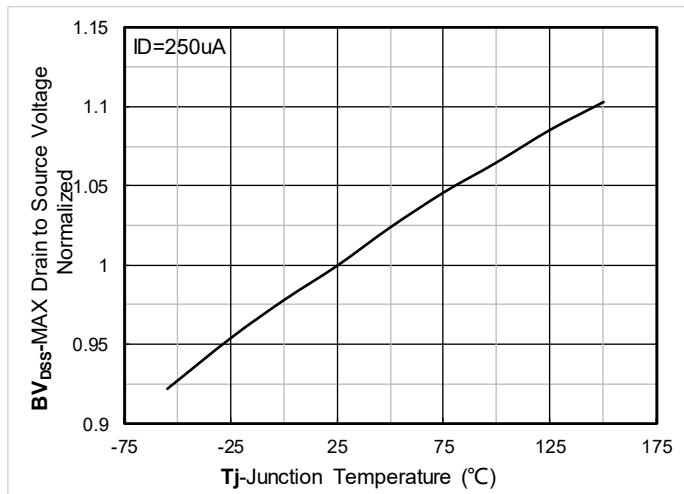


Figure 9. Normalized breakdown voltage

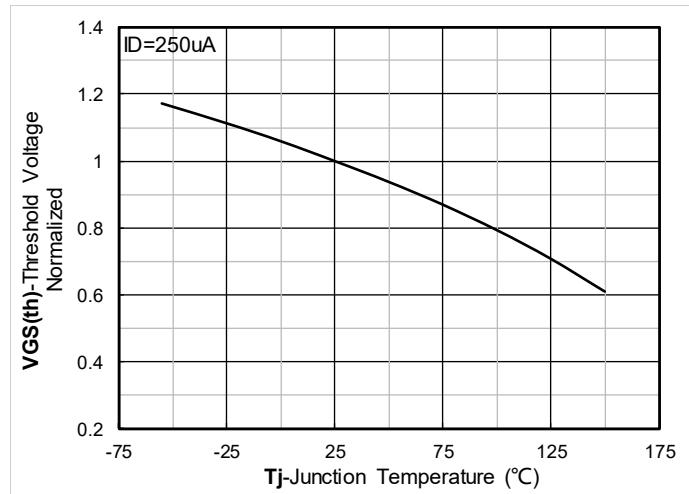


Figure 10. Normalized Threshold voltage

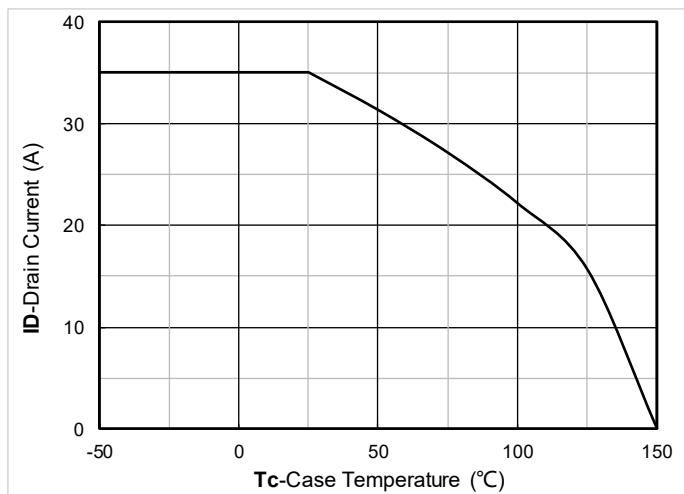


Figure 11. Current dissipation

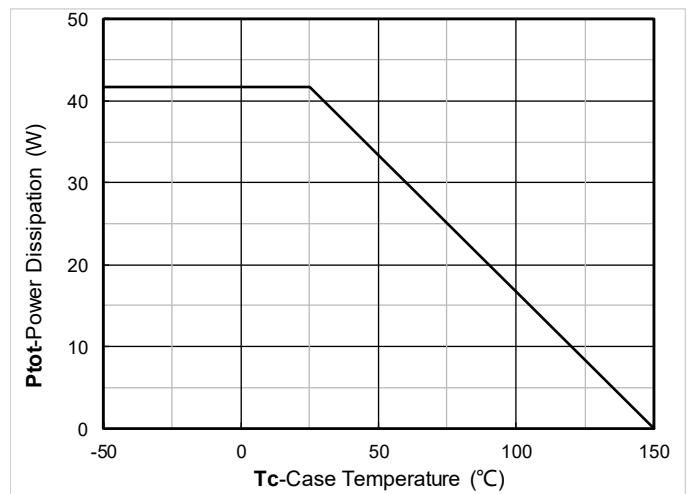


Figure 12. Power dissipation

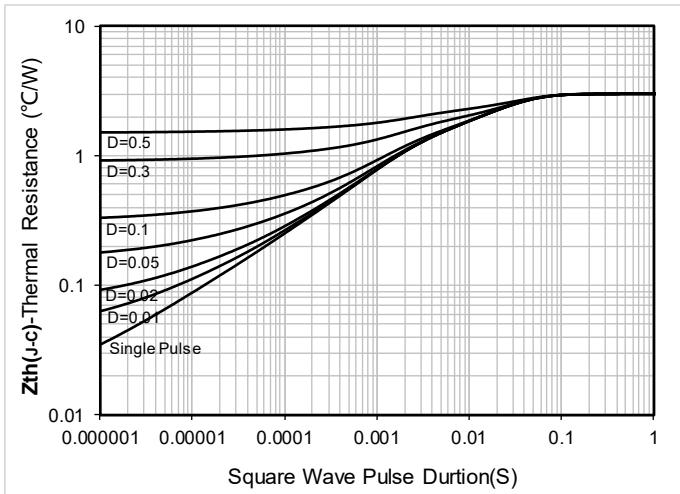


Figure 13. Maximum Transient Thermal Impedance

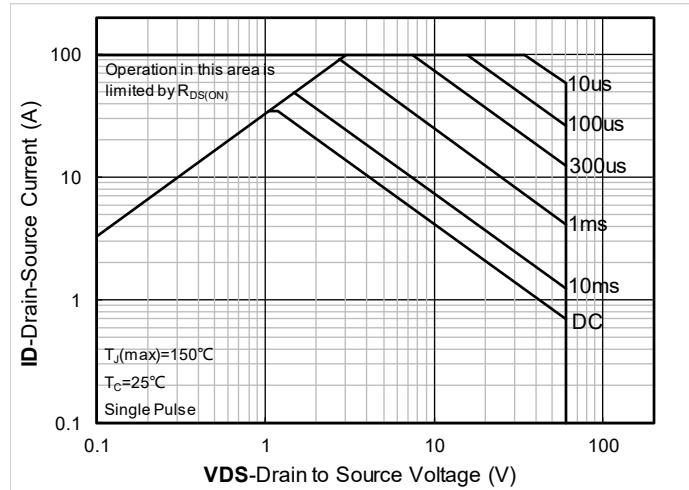


Figure 14. Safe Operation Area

■ Test Circuits & Waveforms

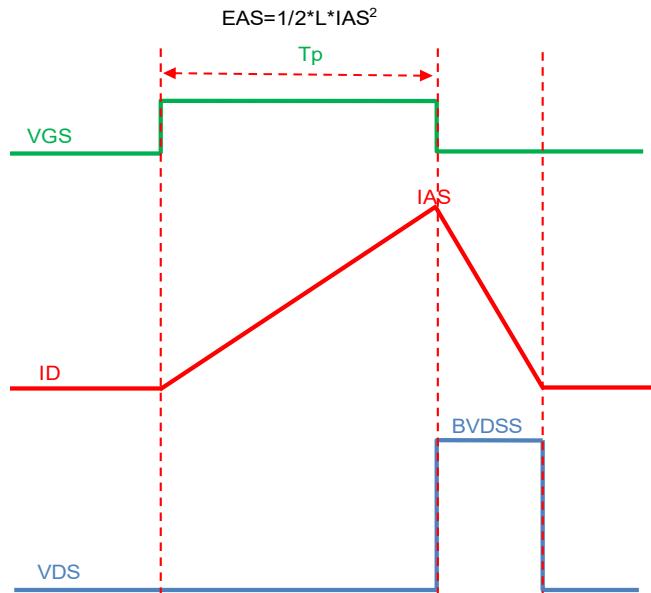
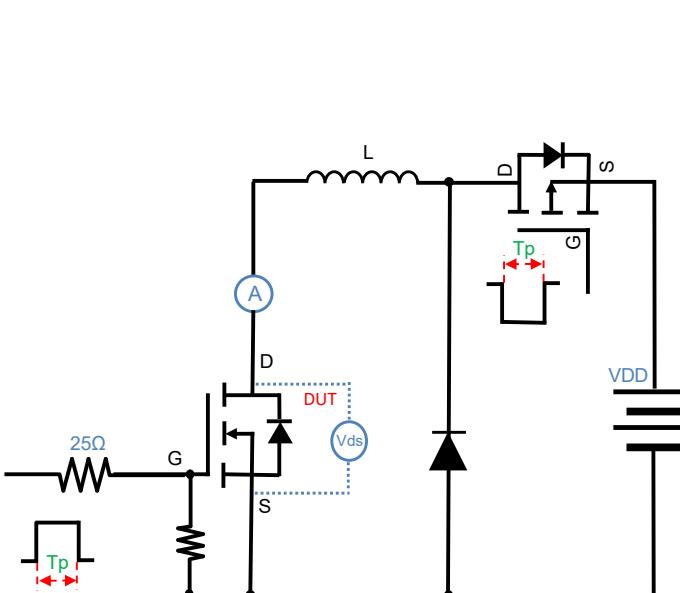


Figure A. Unclamped Inductive Switching (UIS) Test Circuit & Waveform

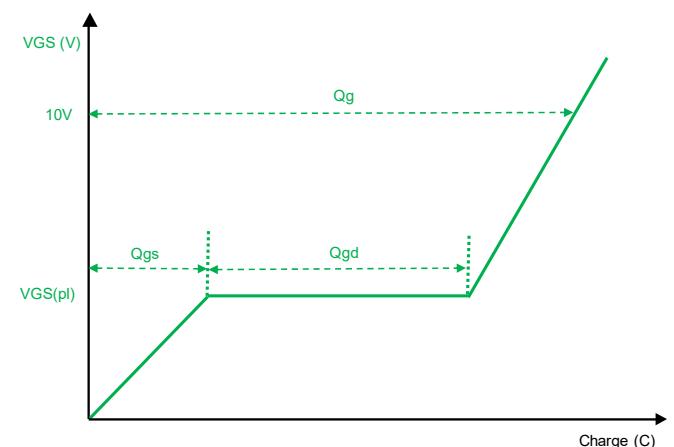
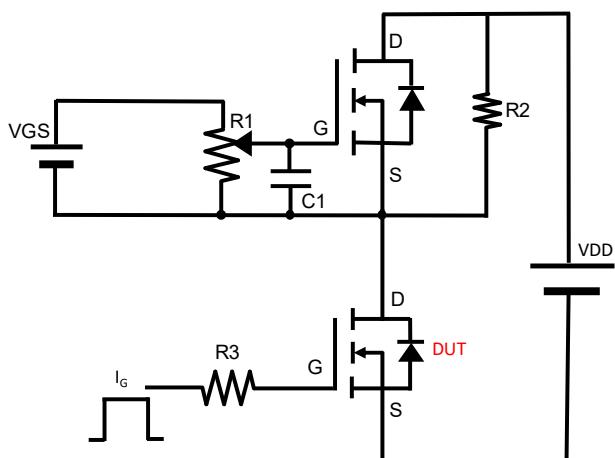


Figure B. Gate Charge Test Circuit & Waveform

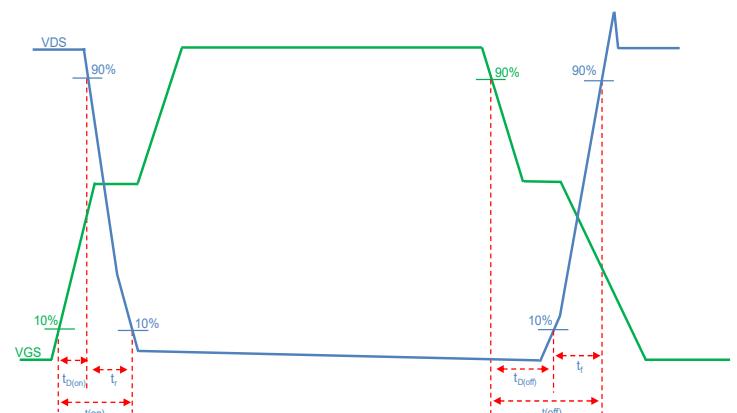
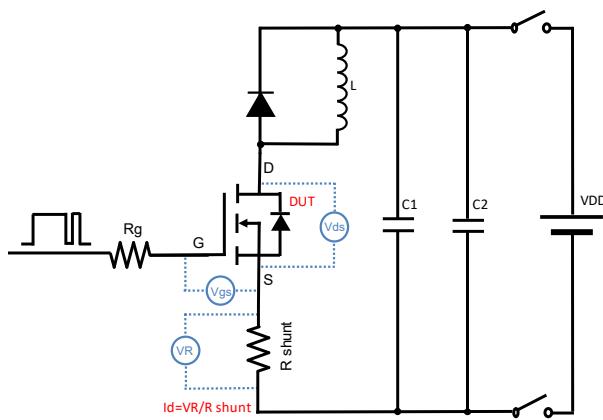


Figure C. Resistive Switching Test Circuit & Waveform

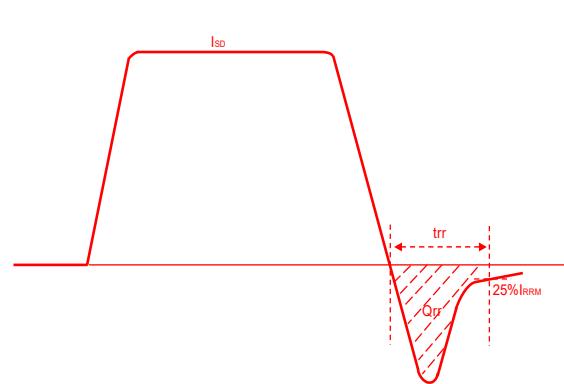
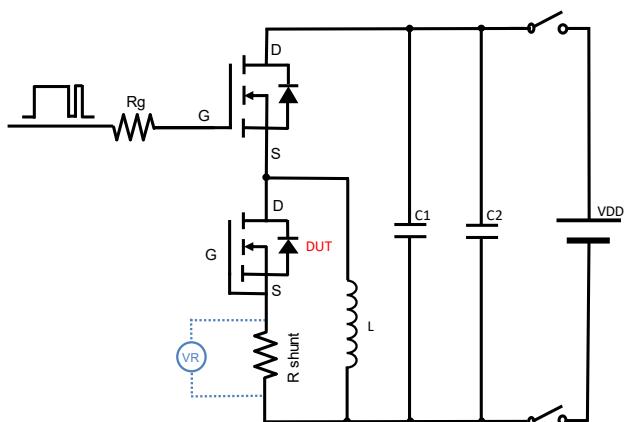
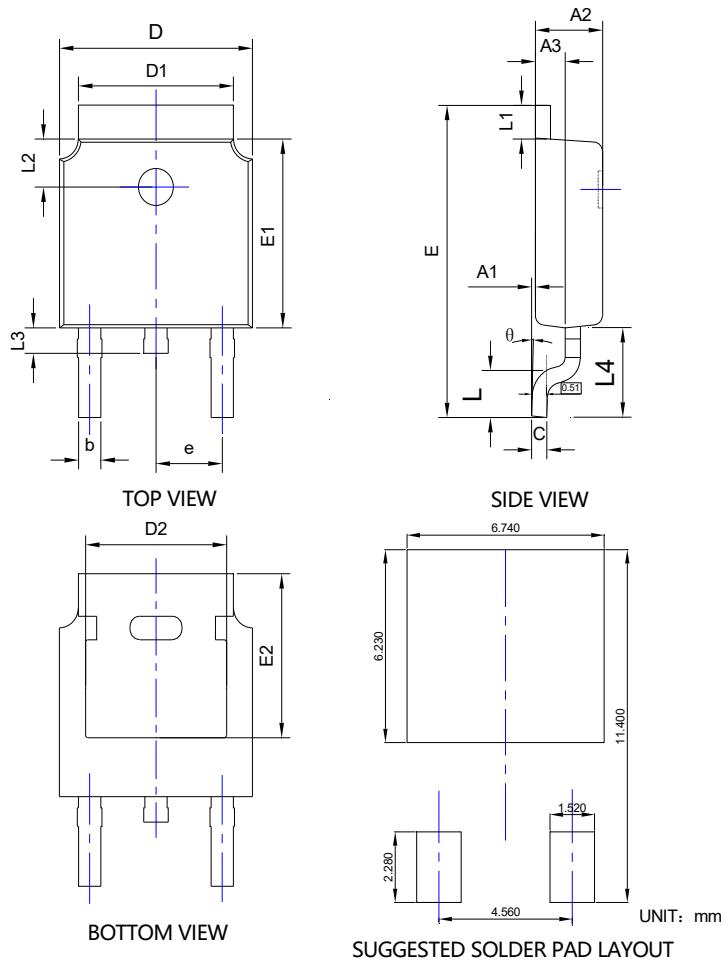


Figure D. Diode Recovery Test Circuit & Waveform



■ TO-252-B Package information



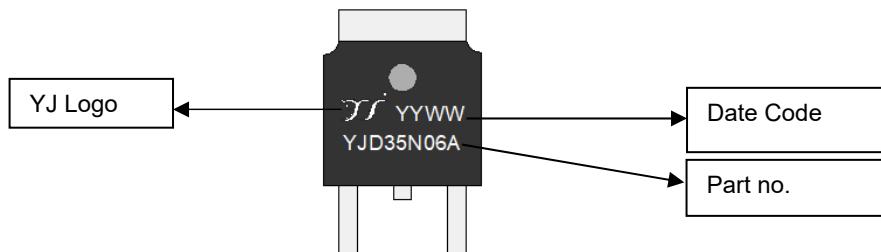
| SYMBOL | DIMENSIONS | | | Millimeter | | |
|----------|------------|-------|-------|------------|--------|--------|
| | MIN. | NOM. | MAX. | MIN. | NOM. | MAX. |
| A1 | 0.000 | -- | 0.008 | 0.000 | -- | 0.200 |
| A2 | 0.087 | 0.091 | 0.094 | 2.200 | 2.300 | 2.400 |
| A3 | 0.035 | 0.039 | 0.043 | 0.900 | 1.000 | 1.100 |
| b | 0.026 | 0.030 | 0.034 | 0.660 | 0.760 | 0.860 |
| c | 0.018 | 0.020 | 0.023 | 0.460 | 0.520 | 0.580 |
| D | 0.256 | 0.260 | 0.264 | 6.500 | 6.600 | 6.700 |
| D1 | 0.203 | 0.209 | 0.215 | 5.150 | 5.300 | 5.450 |
| D2 | 0.181 | 0.189 | 0.195 | 4.600 | 4.800 | 4.950 |
| E | 0.390 | 0.398 | 0.406 | 9.900 | 10.100 | 10.300 |
| E1 | 0.236 | 0.240 | 0.244 | 6.000 | 6.100 | 6.200 |
| E2 | 0.203 | 0.209 | 0.215 | 5.150 | 5.300 | 5.450 |
| e | 0.090BSC | | | 2.286BSC | | |
| L | 0.049 | 0.059 | 0.069 | 1.250 | 1.500 | 1.750 |
| L1 | 0.035 | -- | 0.050 | 0.900 | -- | 1.270 |
| L2 | 0.055 | -- | 0.075 | 1.400 | -- | 1.900 |
| L3 | 0.024 | 0.031 | 0.039 | 0.600 | 0.800 | 1.000 |
| L4 | 0.114REF | | | 2.900REF | | |
| θ | 0° | -- | 10° | 0° | -- | 10° |

NOTE:

- 1.PACKAGE BODY SIZES EXCLUDE MOLD FLASH AND GATE BURRS.
- 2.TOLERANCE 0.1mm UNLESS OTHERWISE SPECIFIED.
- 3.THE PAD LAYOUT IS FOR REFERENCE PURPOSES ONLY.



■ Marking Information



Note:

1. All marking is at middle of the product body
2. All marking is in laser printing
3. YJD35N06A is part no., YYWW is date code, "YY" is year, "WW" is week
4. Body color: Black



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